Non-oxidative coupling of methane over Pd-loaded gallium oxide photocatalysts in a flow reactor

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Abstract

Photocatalytic methane conversion is attractive for utilization of renewable biogas and solar energy to directly produce useful compounds. In the present study, gallium oxide (Ga₂O₃) photocatalyst was examined for non-oxidative coupling of methane (NOCM) around room temperature in a flow reactor. It was found that ethane and hydrogen were continuously yielded at constant rate from methane upon photoirradiation around room temperature, confirming that NOCM can be promoted photocatalytically over Ga₂O₃. In addition, Pd cocatalyst was found to improve the activity of the Ga₂O₃ photocatalyst for NOCM and achieve more than three times higher formation rate of ethane such as $0.22 \,\mu$ mol h⁻¹ in a flow of 10% methane at 30 mL min⁻¹ with 0.8 g of photocatalyst. The methane conversion achieved to 0.006% within a short contact time of 0.8 s, which is higher than the thermodynamically equilibrium conversion.

Keywords: Methane conversion; Ethane production; C-C coupling; Gallium oxide; Palladium; Photocatalysis.

1. Introduction

Methane, the main component of natural gas as well as biogas, has attracted much attention as one of alternative resources for carbon and hydrogen to replace finite resources like petroleum. Among many kinds of catalytic reaction systems, such as reforming, partial oxidation, and oxidative coupling [1–5], non-oxidative coupling of methane (NOCM) is one of desirable reactions to directly produce ethane and hydrogen from methane (eq. 1) [6–8].

$$2 \text{ CH}_4 \rightarrow \text{C}_2\text{H}_6 + \text{H}_2, \qquad \varDelta_r G^{\Theta}_{298\text{K}} = 68.6 \text{ kJ mol}^{-1}$$
 (1)

This is, however, a thermodynamically unfavorable endergonic reaction and the equilibrium constant and equilibrium conversion of this reaction at 298 K are very low such as 9.5×10^{-13} and 0.0002 %, respectively, meaning that this reaction does not take place at 298 K in practice [9]. Although the equilibrium conversion becomes higher at higher temperatures, such as 1.1% and 7.2% at 800 K and 1273 K, respectively, decomposition of methane to carbon and hydrogen (eq. 2) is not negligible at temperatures higher than 800 K because it is thermodynamically more favorable than NOCM [9].

$$CH_4 \rightarrow C + 2H_2, \qquad \varDelta_r G^{\Theta}_{298K} = 50.7 \text{ kJ mol}^{-1}$$
 (2)

Over the last few decades, photocatalyst has become attractive, since it can utilize solar energy to compensate the increase of the chemical potential and to promote thermodynamically unfavorable reactions even at room temperature. In other words, by photocatalysis solar energy can be converted and stored as chemical potential of the products. Photocatalytic NOCM has also been reported since 1998 with various photocatalysts such as SiO₂-Al₂O₃ [10–12], SiO₂-Al₂O₃-TiO₂ [13,14], Ga/SiO₂ [15], and so on [9,15–24]. Most of them are silica-based quantum photocatalysts having atomically

dispersed photocatalytic active sites in silica matrix [25,26], where one of important properties for these photocatalysts would be a reduction-resistant property in the highly reductive conditions, i.e., in the presence of methane, ethane and hydrogen upon photoirradiation. Recently, some silica-based photocatalysts [27,28] and other types of photocatalysts such as plasmonic photocatalyst [29] have been reported for NOCM. However, it is noted that all these studies have examined the photocatalysis in a closed reactor so far, which is not sufficient for exact evaluation of catalytic reaction rate.

In our latest study, gallium oxide (Ga₂O₃) was found to function as a photocatalyst for NOCM [15,30]. Photocatalytic property of Ga₂O₃ has been studied so far for various reactions such as water splitting [31–33], photodegradation of organic compounds [34,35], reforming of methane with carbon dioxide [30,36] or water [37–39], and reduction of carbon dioxide with hydrogen [40] or water [41–46]. In the present study, we examined Ga₂O₃ photocatalyst for NOCM in a flow reactor to elucidate whether the photocatalytic NOCM reaction can be continuously promoted or not, and to evaluate the exact production rates of ethane and hydrogen with the Ga₂O₃ photocatalyst. In addition, we tried to improve the activity of the Ga₂O₃ photocatalyst by loading some additives and found that a Pd cocatalyst improved the activity of the Ga₂O₃ photocatalyst for NOCM.

2. Experimental

2.1 Catalyst preparation

The employed Ga₂O₃ sample was commercially obtained (Ga₂O₃, 99.90%, Kojundo Chemical Laboratory). The following chemicals were used as precursors of additives, Pt(NH₃)₄(NO₃)₂ (99.0%, Nacalai Tesque), RhCl₃ (98%, Wako Pure Chemical), PdCl₂ (99%, Kishida Chemical), AgNO₃ (99.8%, Kishida Chemical), Ni(NO₃)₂·6H₂O (99.9%, Wako Pure Chemical), Fe(NO₃)₃·9H₂O (99%, Nacalai Tesque), In(NO₃)₃·3H₂O (98% Kishida Chemical), Zn(NO₃)₂·6H₂O (99%, Nacalai Tesque), and Sm(NO₃)₃·6H₂O (99.5%, Wako Pure Chemical). Each additive metal or metal oxide was loaded on the Ga₂O₃ sample by an impregnation method: The Ga₂O₃ powder sample (2.0 g) was stirred in an aqueous solution of the precursor (100 mL) at room temperature for 30 min, followed by heating at 353 K to evaporate water to dryness. The obtained powder was dried at 373 K overnight and calcined in an alumina crucible by using an electric muffle furnace at 673 K for 2 h. The metal- or metal oxide-loaded samples are referred to as $M(x)/Ga_2O_3$ sample, where *x* in wt% shows loading amount of the additive (M) calculated as a metal state even if it was oxidized, for example, Pd(0.5)/Ga₂O₃.

2.2 Characterization

The obtained samples were characterized by several techniques. The crystal structure was determined by powder X-ray diffraction with a Shimadzu LabX XRD-6000 X-ray diffractometer using Cu K_{α} radiation (40 kV, 30 mA). Scanning electron microscope (SEM) images were recorded on a JEOL model JSM-890 scanning microscope. Diffuse reflectance UV-visible spectra were recorded by a JASCO V-570 UV/VIS/NIR spectrophotometer equipped with an integrating sphere covered with a BaSO4 reference. The BET specific surface area of the Ga₂O₃ sample was measured by a Quantachrome Monosorb rapid surface area analyzer. The loading amount of Pd was estimated by X-ray fluorescence (XRF) technique using a Shimadzu EDX-8000 energy dispersive X-ray fluorescence spectrometer.

2.3 Photocatalytic activity tests

The photocatalytic activity test for non-oxidative coupling of methane (NOCM) was carried out using a flow reactor shown in Fig. S1 (supplementary information) [47– 50]. The catalyst powder was pressed under 40 MPa and ground into granules of 297-707 μ m (25–50 mesh). The sample granules (0.8 g) were placed into a quartz cell (2 × 2 \times 0.1 cm³, see the picture shown in Fig. S2). The sample was pretreated with an argon flow for 30 min (flow rate = 27 mL min⁻¹) to remove the air from the quartz cell. A flow of mixture of 10% methane in argon (total flow rate = 30 mL min⁻¹) was introduced to the cell for 1 h in dark to achieve stable conditions, where the contact time was nearly 0.8 s and space velocity (SV) was 4500 h^{-1} . The sample was then photoirradiated from a ceramic xenon lamp (PE300BUV, 300 W) to start the photocatalytic NOCM. The irradiation area was 4 cm² and the light intensity as a standard was ca. 20 mW cm⁻², which was measured at 254±10 nm in wavelength. The reaction temperature was increased to be around 320 K by photoirradiation. The outlet gases were analyzed by online gas chromatography equipped with TCD (Shimadzu, GC-8A, argon carrier, a Molecular Sieves 5A, column temperature 323 K) and FID (Shimadzu, GC-8A, argon carrier, a Gaskuropack 54, column temperature 383 K). Methane conversion is calculated based on the amount of obtained products as described in the supplementary information (eq. S1).

3. Results and discussion

3.1. Gallium oxide photocatalyst

The bare Ga_2O_3 powder sample was characterized by some techniques. The XRD pattern of the bare Ga_2O_3 sample (Fig. 1b) was almost similar to that of β -Ga₂O₃ crystal

from a database (Fig. 1a, ICSD#34243 [51]) except for some additional diffraction lines at 24.5, 33.8, 36.2, 41.5, 50.3 and 55.1 degrees assigned to α -Ga₂O₃ phase (ICSD#27431 [52]). Among them the line at 36.2 degrees is somewhat large, which is assignable also to γ -Ga₂O₃ phase (ICSD#152085 [53]). This result means that the commercially obtained Ga₂O₃ sample is of mixed crystal mainly consisting of β -Ga₂O₃ phase including minor amount of α -Ga₂O₃ and γ -Ga₂O₃ phases. The SEM image of the bare Ga₂O₃ sample is shown in Fig. 2A. Pillar-shaped layered particles with some cracks having an average length of 1 µm were observed for the bare Ga₂O₃ sample as reported in the literature [54]. Fig. 3 shows diffuse reflectance UV-visible spectra of the samples. The bare Ga₂O₃ sample exhibited a large absorption in the range of shorter wavelength less than 270 nm (Fig. 3a), from which the bandgap was calculated to be around 4.6 eV. The measured BET specific surface area of the bare Ga₂O₃ sample was 22.8 m² g⁻¹.

Fig. 4 shows time courses of the production rates of ethane (*r*_C) and hydrogen (*r*_H) and the ratio of these reaction rates ($R=rc/r_H$) obtained in the photocatalytic reaction test for NOCM in a flow reactor at around room temperature (*ca.* 320 K) over the bare Ga₂O₃ sample. No product was observed in dark, while upon photoirradiation both ethane and hydrogen were continuously produced with almost constant formation rates at least for 5.5 h and no other product in gas phase was detected. The formation rate for ethane and hydrogen were 0.073 and 0.18 µmol h⁻¹, respectively after 5.5 h under photoirradiation and the ratio of these reaction rates was *R*=0.41 (Table 1, entry 1). The relatively higher rate of hydrogen production than that of ethane would be attributed to the other reaction, which should be a side reaction such as methane decomposition (eq. 2) as discussed later. The methane conversion was calculated to be around 0.002% in constant, which was much higher than the equilibrium conversion [9].

3.2. Metal-loaded gallium oxide photocatalysts

In order to improve the photocatalytic performance of the Ga₂O₃ sample, several metal and metal oxide species were examined as a cocatalyst. Each species was loaded on the Ga₂O₃ photocatalyst by an impregnation method followed by calcination. Representatively, the prepared $Pd(x)/Ga_2O_3$ samples were characterized by XRD, SEM and UV-Vis spectra. XRD patterns of all the $Pd(x)/Ga_2O_3$ (x=0.05, 0.1, and 0.5 wt%) samples were almost the same as those of the bare Ga₂O₃ sample (Fig. 1c-1e). Besides no additional peak appeared in the XRD patterns of these $Pd(x)/Ga_2O_3$ samples, meaning that Pd species is highly dispersed in the crystal lattice of Ga_2O_3 and does not form any new crystal phase. The SEM image of the $Pd(0.5)/Ga_2O_3$ sample is shown in Fig. 2B. Although the fragments of the Ga₂O₃ particles seem to increase during the impregnation and stirred in an aqueous solution, no Pd species were clearly confirmed due to the small loading amount such as 0.5 wt%. Loading of the Pd nanoparticles has no significant effect on the morphology and the particle size of the bare Ga₂O₃ sample. The shape of diffuse reflectance UV-Vis spectra of the $Pd(x)/Ga_2O_3$ samples (Fig. 3b-3d) at shorter wavelength range were almost similar to the bare Ga₂O₃ sample while absorption in the range of 280-500 nm in wavelength increased with increasing Pd loading amount in the $Pd(x)/Ga_2O_3$ samples probably due to the Pd species [55]. This suggests that the impregnation method followed by the calcination at 673 K provides the metal or metal oxide species on the Ga₂O₃ surface without changing the band structure of Ga₂O₃ drastically [37]. The elemental composition of Pd in various $Pd(x)/Ga_2O_3$ (x=0.01-1.0 wt%) samples was analyzed by XRF and the results are listed in Table S1, which confirmed the aimed amount of Pd cocatalyst was almost loaded on each Pd/Ga₂O₃ sample.

Fig. 5 shows time courses of the production rates over the Pt- and Pd-loaded Ga₂O₃ samples. The Pt(0.1)/Ga₂O₃ sample initially exhibited formation of ethane and hydrogen at the rates of 0.04 and 3.01 µmol h⁻¹, respectively (Fig. 5A), which were lower and very higher than those with the bare Ga₂O₃ sample, 0.078 and 0.21 µmol h⁻¹, respectively (Fig. 4). The formation rates then steeply decreased with time and reached 0.023 and 1.6 µmol h⁻¹, respectively after 5.5 h under photoirradiation (also Table 1, entry 2). The production ratio of ethane to hydrogen was very low such as *R*=0.01. After this reaction test, the color of the Pt(0.1)/Ga₂O₃ sample varied from white to grey (Fig. S2). The high hydrogen formation rate and the color change suggested that methane decomposition to carbon and hydrogen (eq. 2) would take place to form coke on the surface of the Pt(0.1)/Ga₂O₃ sample even at 320 K, which would be catalyzed by the additive Pt species.

On the contrary, the Pd(0.5)/Ga₂O₃ photocatalyst exhibited constant formation of ethane and hydrogen after an induction period of a few hours (Fig. 5B). The formation rates of ethane and hydrogen after 5.5 h were 0.22 and 0.23 µmol h⁻¹, respectively (Table 1, entry 6). The ethane formation rate over this sample was more than three times higher than that with the bare Ga₂O₃ sample, 0.073 µmol h⁻¹ (Table 1, entry 1). The production ratio of ethane to hydrogen was almost unity, R=1.0, meaning that photocatalytic NOCM proceeded constantly with high selectivity according to equation 1. The methane conversion was calculated to be 0.008–0.006% during 5.5 h. After the reaction test, the color of the sample did not change so much, supporting that the NOCM selectively took place while methane decomposition would scarcely occur.

Results over the $M(x)/Ga_2O_3$ samples loaded with other additives are also listed in Table 1. Among the examined elements, only Pd and Ag additives enhanced the ethane formation rate with moderate hydrogen production (Table 1, entries 4–7 and Fig. S3).

Effect of loading amount of Pd cocatalysts upon the photocatalytic activity is summarized in Table S1. Among various Pd(*x*)/Ga₂O₃ samples with different loading amounts, the Pd(0.1)/Ga₂O₃ sample showed the highest ethane formation rate of 0.51 μ mol h⁻¹ (Table 1, entry 5), while the Pd(0.5)/ Ga₂O₃ sample exhibited similar formation rates for both ethane and hydrogen with the highest *R* value close to unity as mentioned above (Table 1, entry 6). It is notable that in many cases including the bare Ga₂O₃ photocatalyst, the *R* value was lower than unity, meaning that methane decomposition (eq. 2) tends to take place even at 320 K in the present photocatalytic reaction conditions. Especially, Pt and Rh species exhibited very high production rate of hydrogen and low production rate or no formation of ethane, meaning that these precious metals much enhanced methane decomposition (Table 1, entries 2, 3). Thus, it is suggested that Pd and Ag species can enhance not the methane decomposition but the photocatalytic NOCM.

In the present study, the Pd-loaded Ga₂O₃ photocatalysts were the best photocatalysts for NOCM. Since the formation rate per photocatalyst weight were often reported in literature [27–29], the values for the Pd(0.5)/Ga₂O₃ photocatalyst were tentatively calculated to be 0.28 and 0.29 μ mol h⁻¹ g⁻¹ for ethane and hydrogen formation, respectively. However, it is noted that this evaluation would not be accurate because the reaction rate was not linear to the catalyst weight but rather determined by the irradiation area in this type of flow reactor [56]. Further investigation is required on this point.

3.3. Reaction conditions

Without photoirradiation, NOCM did not proceed over the Pd(0.5)/Ga₂O₃ sample at similar temperature, 323 K, and even at elevated temperatures such as 573 K and 623 K. (Table 1, entries 13–15). Thus, it is evident that NOCM can proceed only under

photoirradiation even at high temperature. At high temperature such as 623 K, the formation of hydrogen only was observed (Table 1, entry 15), meaning that decomposition of CH_4 to C and H_2 would occur in dark, which is supported by the dark grey color of the sample after the reaction (Fig. S4). This implies that thermal energy given at higher temperature can promote not NOCM but methane decomposition.

The photocatalytic NOCM was examined at higher intensities of incident light than 20 mWcm^{-2} , over the Pd(0.05)/Ga₂O₃ photocatalyst for 5 h (Fig. 6). When comparing the results with the intensity of 20 and 40 mWcm⁻², the production rate of ethane was higher for the higher light intensity such as from 0.35 to 0.42 µmol h⁻¹ as expected. But further increase of the light intensity decreased the ethane production rates. Very high light intensities, such as 145 and 230 mWcm⁻², caused methane decomposition predominantly, which was supported by the color change (Fig. S5). The selectivity of ethane is much decreased with an increase in intensity of light higher than 75 mW cm⁻². These observations elucidate that the moderate light intensity is favorable for the selective photocatalytic NOCM over the Pd-loaded Ga₂O₃ photocatalyst.

It is generally accepted that photocatalysis with semiconductor photocatalyst starts from light absorption by the photocatalyst, electrons are photoexcited from the valence band to the conduction band with generating positive holes in the valence band simultaneously, and the generated electrons and holes can react with molecules and ions adsorbed on the surface of the photocatalyst. In the photocatalytic NOCM, the following mechanism has been typically proposed to proceed predominantly [29]. Since methane cannot be further reduced, the first activation of methane must be oxidation by the photogenerated positive hole to form methyl radical and proton on the photocatalyst surface (eq. 3) and two methyl radicals would react to form ethane (eq. 4), while two protons formed should be reduced

by the photogenerated electrons to form hydrogen molecule (eq. 5).

 $CH_4 + h^+ \rightarrow \bullet CH_3 + H^+ \qquad (3)$ $2 \bullet CH_3 \rightarrow C_2H_6 \qquad (4)$ $2 H^+ + 2 e^- \rightarrow H_2 \qquad (5)$

The higher light intensity accelerates the hole oxidation rate, which would promote not only the methyl radical formation (eq. 3) but also further oxidation successively on the surface (eq. 6) before desorption of these produced radical species, along with the hydrogen formation (eq. 5), which is a proposed mechanism for methane decomposition on the surface (eq. 2).

•CH₃ + 3 h⁺
$$\rightarrow$$
 C + 3 H⁺ (6)

As shown in Fig. S6, the reaction with high light intensity (145 mWcm^{-2}) caused a decrease of the ratio of the production rates, *R*, with time. This suggests that, even if the high light intensity increased the reaction rates of both the NOCM (eq. 1) and the methane decomposition (eq. 2), the latter reaction makes coke deposition on the surface and the accumulation of coke deposition on the surface with time would change the surface property to decrease the activity for the photocatalytic NOCM or enhance the methane decomposition. It may also be possible that photoenergy and thermal energy synergistically accelerate the coke formation at higher light intensities since the temperature at 230 mWcm⁻² was measured to be around 160°C.

Effect of methane concentration in the feed gas was examined on the photocatalytic NOCM over the Pd(0.05)/Ga₂O₃ photocatalyst (Fig. 7). When the methane concentration was increased from 10 % and 80%, the ethane production rate increased from 0.35 to 0.51 μ mol h⁻¹, which is kinetically expected. On the other hand, the ratio of the production rates, *R*, decreased with increasing methane concentration at higher methane

concentrations such as 80% and 100%. This means that the rate of methane decomposition become higher in these conditions. The higher concentration of methane should increase the photocatalytic reaction rates of both the NOCM and the methane decomposition, and the latter reaction would give the coke deposition to change the reaction selectivity as discussed above.

Finally, the effect of the flow rates of the feed gas was investigated on the photocatalytic NOCM over the Pd(0.05)/Ga₂O₃ photocatalyst. As demonstrated in Fig. 8, with increasing the flow rate, the ethane formation rate increased while the hydrogen formation rate decreased. Thus, the ratio of the reaction rates, *R*, increased with the flow rate towards the unity, meaning that the NOCM selectivity increased with the flow rate. This suggests that the higher flow rate may help the migration of radical species to enhance the coupling (eq. 4, 5) before further hole oxidation (eq. 6–8), making the NOCM selectivity high. At the slow flow rate such as 10 mL min⁻¹, tiny amount of propane formation was also observed. This proposes that the longer contact time would provide the possibility for the successive coupling reactions to produce higher hydrocarbons such as propane and so on.

4. CONCLUSIONS

In conclusion, by using a flow reactor it was evidenced that the photocatalytic nonoxidative coupling of methane (photocatalytic NOCM) can be promoted over the Pd(0.5 wt%)/Ga₂O₃ photocatalyst almost constantly at least for 5.5 h with the ideal production ratio of ethane and hydrogen, R=1.0, i.e., with high selectivity. The ethane production rate was high such as 0.22 µmol h⁻¹, and methane conversion was 0.006% in the present conditions where the contact time (reaction time) and space velocity (SV) were 0.8 s and 4500 h^{-1} , respectively. The conversion clearly exceeded the thermodynamic equilibrium conversion at this temperature.

It was also found that the moderate light intensity, the moderate methane concentration, and the higher flow rates of the feed gas are favorable for the NOCM reaction over Pd/Ga₂O₃ photocatalysts. Instead, methane decomposition to form coke deposition can proceed as a side reaction under the following conditions, at higher temperature such as 320 K even in dark, at high light intensity, in the high methane concentration, and in a slow flow rate, which is a remaining problem to be studied further.

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REFERENCES

- S. Liu, X. Tan, K. Li, R. Hughes, Methane coupling using catalytic membrane reactors, Catal. Rev. - Sci. Eng. 43 (2001) 147–198. doi:10.1081/CR-100104388.
- [2] J.J. Spivey, G. Hutchings, Catalytic aromatization of methane, Chem. Soc. Rev. 43 (2014) 792–803. doi:10.1039/c3cs60259a.
- [3] X. Guo, G. Fang, G. Li, H. Ma, H. Fan, L. Yu, C. Ma, X. Wu, D. Deng, M. Wei, D. Tan, R. Si, S. Zhang, J. Li, L. Sun, Z. Tang, X. Pan, X. Bao, Direct, Dire

nonoxidative conversion of methane to ethylene, aromatics, and hydrogen., Science. 344 (2014) 616–9. doi:10.1126/science.1253150.

- [4] D. Pakhare, J. Spivey, A review of dry (CO₂) reforming of methane over noble metal catalysts, Chem. Soc. Rev. 43 (2014) 7813–7837. doi:10.1039/c3cs60395d.
- [5] S.A.M. Said, M. Waseeuddin, D.S.A. Simakov, A review on solar reforming systems, Renew. Sustain. Energy Rev. 59 (2016) 149–159. doi:10.1016/j.rser.2015.12.072.
- [6] T. V. Choudhary, E. Aksoylu, D.W. Goodman, Nonoxidative activation of methane, Catal. Rev. - Sci. Eng. 45 (2003) 151–203. doi:10.1081/CR-120017010.
- [7] D. Soulivong, S. Norsic, M. Taoufik, C. Copéret, J. Thivolle-Cazat, S. Chakka, J.M. Basset, Non-oxidative coupling reaction of methane to ethane and hydrogen catalyzed by the silica-supported tantalum hydride: (≡SiO)₂Ta-H, J. Am. Chem. Soc. 130 (2008) 5044–5045. doi:10.1021/ja800863x.
- [8] K.C. Szeto, S. Norsic, L. Hardou, E. Le Roux, S. Chakka, J. Thivolle-Cazat, A. Baudouin, C. Papaioannou, J.M. Basset, M. Taoufik, Non-oxidative coupling of methane catalysed by supported tungsten hydride onto alumina and silica-alumina in classical and H₂ permeable membrane fixed-bed reactors, Chem. Commun. 46 (2010) 3985–3987. doi:10.1039/c0cc00007h.
- [9] L. Yuliati, H. Yoshida, Photocatalytic conversion of methane., Chem. Soc. Rev. 37 (2008) 1592–1602. doi:10.1039/b710575b.
- [10] Y. Kato, H. Yoshida, T. Hattori, Photoinduced non-oxidative coupling of methane over silica-alumina and alumina around room temperature, Chem. Commun. (1998) 2389–2390. doi:10.1039/a806825i.
- [11] H. Yoshida, Y. Kato, T. Hattori, Photoinduced non-oxidative methane coupling

over silica-alumina, in: Stud. Surf. Sci. Catal., 2000: pp. 659–664. doi:10.1016/S0167-2991(00)81033-2.

- [12] H. Yoshida, N. Matsushita, Y. Kato, T. Hattori, Active sites in sol-gel prepared silica-alumina for photoinduced non-oxidative methane coupling, Phys. Chem. Chem. Phys. 4 (2002) 2459–2465. doi:10.1039/b111101a.
- [13] Y. Kato, N. Matsushita, H. Yoshida, T. Hattori, Highly active silica-alumina-titania catalyst for photoinduced non-oxidative methane coupling, Catal. Commun. 3 (2002) 99–103. doi:10.1016/S1566-7367(02)00056-0.
- [14] H. Yoshida, N. Matsushita, Y. Kato, T. Hattori, Synergistic Active Sites on SiO₂
 -Al₂O₃-TiO₂ Photocatalysts for Direct Methane Coupling, J. Phys. Chem. B. 107
 (2003) 8355–8362. doi:10.1021/jp034458+.
- [15] L. Yuliati, T. Hattori, H. Itoh, H. Yoshida, Photocatalytic nonoxidative coupling of methane on gallium oxide and silica-supported gallium oxide, J. Catal. 257 (2008) 396–402. doi:10.1016/j.jcat.2008.05.022.
- [16] K. Shimura, H. Yoshida, Semiconductor photocatalysts for non-oxidative coupling, dry reforming and steam reforming of methane, Catal. Surv. from Asia. 18 (2014) 24–33. doi:10.1007/s10563-014-9165-z.
- Y. Kato, H. Yoshida, A. Satsuma, T. Hattori, Photoinduced non-oxidative coupling of methane over H-zeolites around room temperature, Microporous Mesoporous Mater. 51 (2002) 223–231. doi:10.1016/S1387-1811(02)00268-8.
- [18] H. Yoshida, M.G. Chaskar, Y. Kato, T. Hattori, Active sites on silica-supported zirconium oxide for photoinduced direct methane conversion and photoluminescence, J. Photochem. Photobiol. A Chem. 160 (2003) 47–53. doi:10.1016/S1010-6030(03)00220-X.

- [19] L. Yuliati, T. Hamajima, T. Hattori, H. Yoshida, Highly dispersed Ce(III) species on silica and alumina as new photocatalysts for non-oxidative direct methane coupling, Chem. Commun. (2005) 4824–4826. doi:10.1039/b507698f.
- [20] L. Yuliati, T. Hattori, H. Yoshida, Highly dispersed magnesium oxide species on silica as photoactive sites for photoinduced direct methane coupling and photoluminescence, Phys. Chem. Chem. Phys. 7 (2005) 195–201. doi:10.1039/b410089a.
- [21] L. Yuliati, M. Tsubota, A. Satsuma, H. Itoh, H. Yoshida, Photoactive sites on pure silica materials for nonoxidative direct methane coupling, J. Catal. 238 (2006) 214–220. doi:10.1016/j.jcat.2005.12.002.
- [22] L. Yuliati, H. Itoh, H. Yoshida, Modification of Highly Dispersed Cerium Oxides on Silica with Highly Dispersed Titanium Oxides as a New Photocatalyst Design for Nonoxidative Direct Methane Coupling, Chem. Lett. 35 (2006) 932–933. doi:10.1246/cl.2006.932.
- [23] L. Yuliati, H. Itoh, H. Yoshida, Photocatalytic direct conversion of methane on silica-titania catalysts, Stud. Surf. Sci. Catal. 172 (2007) 457–460.
- [24] L. Yuliati, T. Hamajima, T. Hattori, H. Yoshida, Nonoxidative coupling of methane over supported ceria photocatalysts, J. Phys. Chem. C. 112 (2008) 7223–7232. doi:10.1021/jp712029w.
- [25] H. Yoshida, Silica-based quantum photocatalysts for selective reactions, Curr.Opin. Solid State Mater. Sci. 7 (2003) 435–442. doi:10.1016/j.cossms.2004.03.006.
- [26] H. Yoshida, Active sites of silica-based quantum photocatalysts for non-oxidative reactions, Catal. Surv. from Asia. 9 (2005) 1–9. doi:10.1007/s10563-005-3330-3.
- [27] L. Li, G.D. Li, C. Yan, X.Y. Mu, X.L. Pan, X.X. Zou, K.X. Wang, J.S. Chen,

Efficient sunlight-driven dehydrogenative coupling of methane to ethane over a Zn⁺-modified zeolite, Angew. Chemie - Int. Ed. 50 (2011) 8299–8303. doi:10.1002/anie.201102320.

- [28] S. Wu, X. Tan, J. Lei, H. Chen, L. Wang, J. Zhang, Ga-Doped and Pt-Loaded Porous TiO₂ -SiO₂ for Photocatalytic Nonoxidative Coupling of Methane, J. Am. Chem. Soc. 141 (2019) 6592–6600. doi:10.1021/jacs.8b13858.
- [29] L. Meng, Z. Chen, Z. Ma, S. He, Y. Hou, H.H. Li, R. Yuan, X.H. Huang, X. Wang, X. Wang, J. Long, Gold plasmon-induced photocatalytic dehydrogenative coupling of methane to ethane on polar oxide surfaces, Energy Environ. Sci. 11 (2018) 294–298. doi:10.1039/c7ee02951a.
- [30] L. Yuliati, H. Itoh, H. Yoshida, Photocatalytic conversion of methane and carbon dioxide over gallium oxide, Chem. Phys. Lett. 452 (2008) 178–182. doi:10.1016/j.cplett.2007.12.051.
- [31] T. Yanagida, Y. Sakata, H. Imamura, Photocatalytic Decomposition of H₂O into H₂ and O₂ over Ga₂O₃ Loaded with NiO, Chem. Lett. 33 (2004) 726–727. doi:10.1246/cl.2004.726.
- [32] Y. Sakata, Y. Matsuda, T. Nakagawa, R. Yasunaga, H. Imamura, K. Teramura, Remarkable improvement of the photocatalytic activity of Ga₂O₃ towards the overall splitting of H₂O, ChemSusChem. 4 (2011) 181–184. doi:10.1002/cssc.201000258.
- [33] Y. Sakata, T. Nakagawa, Y. Nagamatsu, Y. Matsuda, R. Yasunaga, E. Nakao, H. Imamura, Photocatalytic properties of gallium oxides prepared by precipitation methods toward the overall splitting of H₂O, J. Catal. 310 (2014) 45–50. doi:10.1016/j.jcat.2013.06.025.

- [34] Y. Hou, X. Wang, L. Wu, Z. Ding, X. Fu, Efficient decomposition of benzene over a β-Ga₂O₃ photocatalyst under ambient conditions, Environ. Sci. Technol. 40 (2006) 5799–5803. doi:10.1021/es061004s.
- [35] T. Shao, P. Zhang, L. Jin, Z. Li, Photocatalytic decomposition of perfluorooctanoic acid in pure water and sewage water by nanostructured gallium oxide, Appl. Catal. B Environ. 142–143 (2013) 654–661. doi:10.1016/j.apcatb.2013.05.074.
- [36] H. Yoshida, K. Maeda, Preparation of gallium oxide photocatalysts for reduction of carbon dioxide, Stud. Surf. Sci. Catal. 175 (2010) 351–354. doi:10.1016/S0167-2991(10)75058-8.
- [37] K. Shimura, T. Yoshida, H. Yoshida, Photocatalytic activation of water and methane over modified gallium oxide for hydrogen production, J. Phys. Chem. C. 114 (2010) 11466–11474. doi:10.1021/jp1012126.
- [38] K. Shimura, K. Maeda, H. Yoshida, Thermal Acceleration of Electron Migration in Gallium Oxide Photocatalysts, J. Phys. Chem. C. 115 (2011) 9041–9047. doi:10.1021/jp110824n.
- [39] K. Shimura, H. Yoshida, Effect of doped zinc species on the photocatalytic activity of gallium oxide for hydrogen production, Phys. Chem. Chem. Phys. 14 (2012) 2678–2684. doi:10.1039/c2cp23220k.
- [40] K. Teramura, H. Tsuneoka, T. Shishido, T. Tanaka, Effect of H₂ gas as a reductant on photoreduction of CO₂ over a Ga₂O₃ photocatalyst, Chem. Phys. Lett. 467 (2008) 191–194. doi:10.1016/j.cplett.2008.10.079.
- [41] N. Yamamoto, T. Yoshida, S. Yagi, Z. Like, T. Mizutani, S. Ogawa, H. Nameki, H. Yoshida, The Influence of the Preparing Method of a Ag/Ga₂O₃ Catalyst on its Activity for Photocatalytic Reduction of CO₂ with Water, E-Journal Surf. Sci.

Nanotechnol. 12 (2014) 263-268. doi:10.1380/ejssnt.2014.263.

- [42] K. Teramura, Z. Wang, S. Hosokawa, Y. Sakata, T. Tanaka, A doping technique that suppresses undesirable H₂ evolution derived from overall water splitting in the highly selective photocatalytic conversion of CO₂ in and by water, Chem. A Eur. J. 20 (2014) 9906–9909. doi:10.1002/chem.201402242.
- [43] M. Yamamoto, T. Yoshida, N. Yamamoto, T. Nomoto, Y. Yamamoto, S. Yagi, H.
 Yoshida, Photocatalytic reduction of CO₂ with water promoted by Ag clusters in Ag/Ga₂O₃ photocatalysts, J. Mater. Chem. A. 3 (2015) 16810–16816.
 doi:10.1039/c5ta04815j.
- [44] Y.X. Pan, Z.Q. Sun, H.P. Cong, Y.L. Men, S. Xin, J. Song, S.H. Yu, Photocatalytic CO₂ reduction highly enhanced by oxygen vacancies on Pt-nanoparticle-dispersed gallium oxide, Nano Res. 9 (2016) 1689–1700. doi:10.1007/s12274-016-1063-4.
- [45] Z. Wang, K. Teramura, Z. Huang, S. Hosokawa, Y. Sakata, T. Tanaka, Tuning the selectivity toward CO evolution in the photocatalytic conversion of CO₂ with H₂O through the modification of Ag-loaded Ga₂O₃ with a ZnGa₂O₄ layer, Catal. Sci. Technol. 6 (2016) 1025–1032. doi:10.1039/c5cy01280e.
- [46] Y. Kawaguchi, M. Akatsuka, M. Yamamoto, K. Yoshioka, A. Ozawa, Y. Kato, T. Yoshida, Preparation of gallium oxide photocatalysts and their silver loading effects on the carbon dioxide reduction with water, J. Photochem. Photobiol. A Chem. 358 (2018) 459–464. doi:10.1016/j.jphotochem.2017.11.010.
- [47] H. Yoshida, S. Kato, K. Hirao, J.-I. Nishimoto, T. Hattori, Photocatalytic steam reforming of methane over platinum-loaded semiconductors for hydrogen production, Chem. Lett. 36 (2007) 430–431. doi:10.1246/cl.2007.430.
- [48] H. Yoshida, K. Hirao, J.-I. Nishimoto, K. Shimura, S. Kato, H. Itoh, T. Hattori,

Hydrogen production from methane and water on platinum loaded titanium oxide photocatalysts, J. Phys. Chem. C. 112 (2008) 5542–5551. doi:10.1021/jp077314u.

- [49] K. Shimura, S. Kato, T. Yoshida, H. Itoh, T. Hattori, H. Yoshida, Photocatalytic steam reforming of methane over sodium tantalate, J. Phys. Chem. C. 114 (2010) 3493–3503. doi:10.1021/jp902761x.
- [50] A. Yamamoto, S. Mizuba, Y. Saeki, H. Yoshida, Platinum loaded sodium tantalate photocatalysts prepared by a flux method for photocatalytic steam reforming of methane, Appl. Catal. A Gen. 521 (2016) 125–132. doi:10.1016/j.apcata.2015.10.031.
- [51] S. Geller, Crystal Structure of β-Ga₂O₃ Cite, J. Chem. Phys. 33 (1960) 676.
 doi:10.1063/1.1731237.
- [52] M. Marezio, J. P. Remeika, Bond lengths in α-Ga₂O₃ structure and high-pressure phase of Ga_{2-x}Fe_xO₃, J. Chem. Phys. 46 (1967) 1862. doi:10.1063/1.1840945.
- [53] M. Zinkevich, F.M. Morales, H. Nitsche, M. Ahrens, M. Rühle, F. Aldinger, Microstructural and thermodynamic study of γ-Ga₂O₃, Zeitschrift Fuer Met. 95 (2004) 756–762. doi:10.3139/146.018018.
- [54] S. Iguchi, Y. Hasegawa, K. Teramura, S. Kidera, S. Kikkawa, S. Hosokawa, H. Asakura, T. Tanaka, Drastic improvement in the photocatalytic activity of Ga₂O₃ modified with Mg-Al layered double hydroxide for the conversion of CO₂ in water, Sustainable Energy Fuels 1 (2017) 1740-1747. doi: 10.1039/c7se00204a.
- [55] A. Barrera, F. Tzompantzi, J.M. Padilla, J.E. Casillas, G. Jácome-Acatitla, M.E. Cano, R. Gómez, Reusable PdO/Al₂O₃-Nd₂O₃ photocatalysts in the UV photodegradation of phenol, Appl. Catal. B Environ. 144 (2014) 362–368. doi:10.1016/j.apcatb.2013.07.024.

 [56] H. Yoshida, S. Mizuba, A. Yamamoto, Preparation of sodium hexatitanate photocatalysts by a flux method for photocatalytic steam reforming of methane, Catal. Today. 334 (2019) 30–36. doi:10.1016/j.cattod.2019.02.055.

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Entry	Samples	Production rates $[\mu mol h^{-1}]$		<i>R</i> ^[c]
		C_2H_6	H ₂	
1	Ga ₂ O ₃	0.073	0.18	0.41
2	Pt(0.1)/Ga2O3	0.023	1.6	0.014
3	Rh(0.1)/Ga2O3	n.d. ^[d]	0.72	
4	Pd(0.05)/Ga ₂ O ₃	0.35	0.85	0.41
5	Pd(0.1)/Ga ₂ O ₃	0.51	1.2	0.42
6	Pd(0.5)/Ga ₂ O ₃	0.22	0.23	0.96
7	Ag(0.1)/Ga ₂ O ₃	0.17	0.23	0.74
8	Ni(0.1)/Ga ₂ O ₃	n.d. ^[d]	0.10	
9	Fe(0.1)/Ga ₂ O ₃	n.d. ^[d]	0.13	
10	In(0.1)/Ga ₂ O ₃	0.045	0.20	0.23
11	Zn(0.1)/Ga ₂ O ₃	0.088	0.14	0.63
12	Sm(0.1)/Ga ₂ O ₃	0.049	0.16	0.31
13	Pd(0.5)/Ga ₂ O ₃ ^[e]	n.d. ^[d]	n.d. ^[d]	
14	Pd(0.5)/Ga2O3 ^[f]	n.d. ^[d]	n.d. ^[d]	
15	Pd(0.5)/Ga ₂ O ₃ ^[g]	n.d. ^[d]	0.36	

Table 1. Results of photocatalytic reaction test for NOCM over the bare Ga_2O_3 sample and various $M(x)/Ga_2O_3$ samples. ^[a,b]

[a] Reaction conditions were the same as those described in the caption of Fig. 4. The values of production rates were recorded at 5.5 h later from the start of the photoirradiation. [b] The Ga₂O₃ sample used here was commercially obtained. Various $M(x)/Ga_2O_3$ samples were prepared by an impregnation method, where *x* shows loading amount of the additive metal oxide or metals M in wt%, for example, Pd(0.5)/Ga₂O₃. [c] Calculated as follows: R = (production rate of ethane)/(production rate of hydrogen). [d] n.d. = not detected. [e–g] The reaction tests were carried out at 323 K [e], 573 K [f], and 623 K [g], respectively in dark.



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